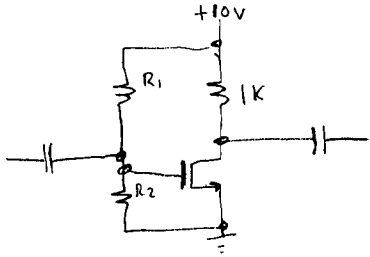


Example: Design using MOSFET as a resistor

(2A)
1

Recall this amplifier:

(1B-5)



$$\mu = 600 \frac{\text{cm}^2}{\text{V}\cdot\text{s}} = 6 \times 10^{-2} \frac{\text{m}^2}{\text{V}\cdot\text{s}}$$

$$t_{ox} = 0.01 \mu\text{m} = 10^{-8} \text{m}$$

$$\Rightarrow 'k' = 2 \times 10^{-4} \quad \lambda = 0.01$$

$$V_{TH} = 1 \quad (\text{not the same as the previous example, but that's what we will use})$$

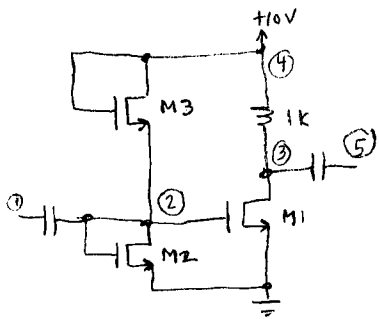
$$G_{mid} = -10 \quad (-9.6) \quad L = 1 \mu\text{m} \quad W = 50 \mu\text{m}$$

$$V_{GS} - V_{TH} = 1 \Rightarrow V_{GS} = 2$$

With resistors - $R_1 = 8 \text{ meg}$
 $R_2 = 2 \text{ meg}$.

We want to replace R_1, R_2 with MOSFETs.

Choose a current: 1 mA (Arbitrary, keep it low).
(Same as resistors).



(M2) set $\frac{W}{L}$ for 1 mA with $V_{GS} = 2$

$$I_D = \frac{1}{2} k' \frac{W}{L} (V_{GS} - V_{TH})^2$$

$$10^{-6} = \left(\frac{1}{2}\right) (2 \times 10^{-4}) \frac{W}{L} (2 - 1)^2$$

$$10^{-6} = 10^{-4} \frac{W}{L}$$

$$\frac{W}{L} = \frac{10^{-6}}{10^{-4}} = \frac{1 \mu\text{m}}{100 \mu\text{m}}$$

(M3) set $\frac{W}{L}$ for 1 mA with $V_{GS} = 8$

$$10^{-6} = \left(\frac{1}{2}\right) (2 \times 10^{-4}) \frac{W}{L} (8 - 1)^2$$

$$\frac{W}{L} = \frac{10^{-6}}{49 \times 10^{-4}} = \frac{1 \mu\text{m}}{4900 \mu\text{m}} \leftarrow \text{Very long channel. - not good.}$$

log sim-log

```
list
M1 (3 2 0 0) nn l=1.u w=50.u
M2 (2 2 0 0) nn l=100.u w=1.u
M3 (4 4 2 0) nn l=0.0049 w=1.u
Rd (4 3) 1.K
Vdd (4 0) DC 10.
Cin (1 2) 1.u
Cout (3 5) 1.u
Vin (1 0) GENERATOR
.model nn nmos (level=1 tnom=27. fc=0.5 pb=0.8 cj=0. mj=0.5 cjsw=0. mjsw=0.5 i
s=10.f rsh=0. cgso=0. cgdo=0. cgbo=0. vto=1. gamma=0. phi=0.6 lambda=0.01 ld=
0. uo=600. tpg=1 kp=200.u)
**(* cox=0.)
print op v(nodes)
op
# v(1) v(2) v(3) v(4) v(5)
300.15 0. 2.0251 4.5094 10. 0.
print op id(m*)
op
# id(M1) id(M2) id(M3)
300.15 0.0054906 1.072u 1.072u
print ac v(nodes)
ac 1k
#Freq v(1) v(2) v(3) v(4) v(5)
1.K 1. 1. 10.178 101.78n 10.178
print ac z(vin)
ac
#Freq z(Vin)
1.K 413.31K ← why so low?
print op region(m*)
op
# region(M1) region(M2) region(M3)
300.15 7. 7. 7.
print op gds(m*)
op
# gds(M1) gds(M2) gds(M3)
300.15 52.537u 10.507n 9.9285n
build
m3 4 4 2 2 nn w=1u l=4900u ← R ≈ 100 meg
```

```
list
M1 (3 2 0 0) nn l=1.u w=50.u
M2 (2 2 0 0) nn l=100.u w=1.u
M3 (4 4 2 2) nn l=0.0049 w=1.u
Rd (4 3) 1.K
Vdd (4 0) DC 10.
Cin (1 2) 1.u
Cout (3 5) 1.u
Vin (1 0) GENERATOR
.model nn nmos (level=1 tnom=27. fc=0.5 pb=0.8 cj=0. mj=0.5 cjsw=0. mjsw=0.5 i
s=10.f rsh=0. cgso=0. cgdo=0. cgbo=0. vto=1. gamma=0. phi=0.6 lambda=0.01 ld=
0. uo=600. tpg=1 kp=200.u)
**(* cox=0.)
print op v(nodes)
op
# v(1) v(2) v(3) v(4) v(5)
300.15 0. 2.0251 4.5093 10. 0.
save amp2a1.ckt
```

HW
4,2
P.361: 19, 20, 21, 22
P.362: 32, 33
4.3 all exercises

```
get amp2a1.ckt
```

```
print op v(nodes)
```

```
op
#          v(1)      v(2)      v(3)      v(4)      v(5)
300.15    0.        2.0251    4.5093    10.       0.
```

```
print op gm(m*)
```

```
op
#          gm(M1)     gm(M2)     gm(M3)
300.15    0.010713    2.0916u    307.4n
```

```
list
```

```
M1 ( 3 2 0 0 ) nn l= 1.u w= 50.u
M2 ( 2 2 0 0 ) nn l= 100.u w= 1.u
M3 ( 4 4 2 2 ) nn l= 0.0049 w= 1.u
Rd ( 4 3 ) 1.K
Vdd ( 4 0 ) DC 10.
Cin ( 1 2 ) 1.u
Cout ( 3 5 ) 1.u
Vin ( 1 0 ) GENERATOR
```

```
.model nn nmos (level=1 tnom=27. fc= 0.5 pb= 0.8 cj= 0. mj= 0.5 cjsw= 0.
mjsw= 0.5 is= 10.f rsh= 0. cgso= 0. cgdo= 0. cgbo= 0. vto= 1. gamma= 0. ph
i= 0.6 lambda= 0.01 ld= 0. uo= 600. tpg=1 kp= 200.u)
*+(* cox= 0.)
```

```
del m2
build
i3 2 0 dc 1u
```

```
op
#          gm(M1)     gm(M3)
300.15    0.012808    296.57n
```

```
print op v(nodes)
```

```
op
#          v(1)      v(2)      v(3)      v(4)      v(5)
300.15    0.        2.2563    1.9547    10.       0.
```

```
build
build
```

```
list
```

```
M1 ( 3 2 0 0 ) nn l= 1.u w= 50.u
M3 ( 4 4 2 2 ) nn l= 0.0049 w= 1.u
Rd ( 4 3 ) 1.K
Vdd ( 4 0 ) DC 10.
Cin ( 1 2 ) 1.u
Cout ( 3 5 ) 1.u
Vin ( 1 0 ) GENERATOR
```

```
.model nn nmos (level=1 tnom=27. fc= 0.5 pb= 0.8 cj= 0. mj= 0.5 cjsw= 0.
mjsw= 0.5 is= 10.f rsh= 0. cgso= 0. cgdo= 0. cgbo= 0. vto= 1. gamma= 0. ph
i= 0.6 lambda= 0.01 ld= 0. uo= 600. tpg=1 kp= 200.u)
*+(* cox= 0.)
```

```
I3 ( 2 0 ) DC 1.u
build
i3 2 0 dc 1.1u
```

```
op
#          v(1)      v(2)      v(3)      v(4)      v(5)
300.15    0.        1.9376    5.369     10.       0.
```

```
print ac v(nodes) z(vin)
```

```
ac 1k
#Freq      v(1)      v(2)      v(3)      v(4)      v(5)      z(Vin)
1.K        1.        1.        9.463     94.627n   9.463     3.1086Meg
```

```
print op gm(m3) gds(m3)
```

```
op
#          gm(M3)     gds(M3)
300.15    311.5n    10.179n
```

```
get amp2a1.ckt
```

```
print op v(nodes)
```

```
op
#          v(1)      v(2)      v(3)      v(4)      v(5)
```

2A
3

300.15 0. 2.0251 4.5093 10. 0.

```
print ac v(nodes) z(vin)
ac 1k
#Freq      v(1)      v(2)      v(3)      v(4)      v(5)      z(Vin)
1.K        1.        1.        10.178    101.78n   10.178    413.31K
del m3
build
i3 4 2 dc 1u

op
#          v(1)      v(2)      v(3)      v(4)      v(5)
300.15    0.        1.9902    4.8594    10.       0.
ac
#Freq      v(1)      v(2)      v(3)      v(4)      v(5)      z(Vin)
1.K        1.        1.        9.8979    98.979n   9.8979    492.71K
```

2A
4

Course web site

<http://www.kettering.edu/~vadavis/>

→ class/ee420-electronics2

gnucap on sun:

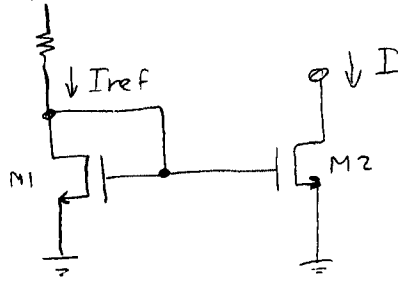
put vadavis/public/bin
in your path then "gnucap"
or -- "vadavis/public/bin/gnucap"

Current mirror

2A
5

→ How to make a current source.

You need two parts: A reference
The source



If M1 and M2 are identical, and we ignore λ and it remains in saturation $I = I_{ref}$.

We can make unequal currents by scaling W and L.

For $2I$ use $2W$, etc.

Basis ---- V_{GS} is the same, so I should be the same.

We can connect as many as we want:

To design: Set M1 W & L for desired reference current
Size M2 to get the desired current there.

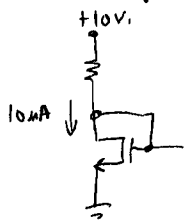
Example: $I_{ref} = 10 \mu A$ $I = 100 \mu A$ $V_{DD} = 10V$.
 $V_{TH} = 2$ $K' = 2 \times 10^{-4} \frac{A}{V^2}$ $L_{min} = W_{min} = 1 \mu m$.

$$I = \frac{1}{2} K' \frac{W}{L} (V_{GS} - V_{TH})^2$$

We can choose W, L then find V_{GS}
or choose V_{GS} then find W/L.

Let's choose $W=L$, then find V_{GS}

$$10^{-5} = \frac{1}{2} (2 \times 10^{-4}) (1) (V_{GS} - V_{TH})^2$$

$$(V_{GS} - V_{TH})^2 = \frac{10^{-5}}{10^{-4}} = 0.1 \quad V_{GS} - V_{TH} = .316 \quad V_{GS} = 2.316$$


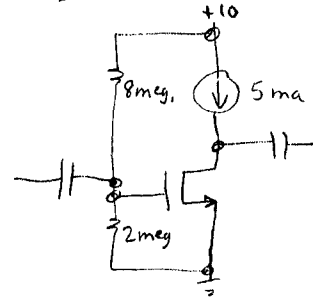
Now, size the mirror:

2A
6

For $10 \times$ the current, use $10 \times$ the width.
 $W = 10 \mu m$.

Caveats: ① It only works in saturation.
② Lambda really matters, sometimes.

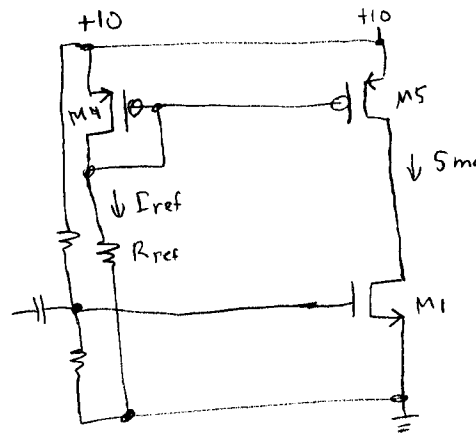
Example Start with the example from 1B-8



Same process as before -
P-channel process $K' = 1 \times 10^{-4}$
otherwise the same.

Want to use a MOSFET for the current source.

Use P-channel MOSFETS.



Choose $I_{ref} = 0.1 \text{ ma}$, $W=L$

$$I = \frac{1}{2} K' \frac{W}{L} (V_{GS} - V_{TH})^2$$

$$0.1 \times 10^{-6} = \frac{1}{2} (10^{-4}) \frac{1}{1} (V_{GS} - V_{TH})^2$$

$$\frac{0.1 \times 10^{-6}}{0.5 \times 10^{-4}} = (V_{GS} - V_{TH})^2$$

$$0.002 = (V_{GS} - V_{TH})^2$$

$$0.045 = V_{GS} - V_{TH}$$

$$V_{GS} = V_{TH} + 0.045 = 2.045$$

$$R_{ref} = \frac{8V}{0.1 \text{ ma}} = 80 \text{ K}$$

Then make W of $M_5 = \frac{5}{0.1} \times \text{width of } M_4 = 50 \mu m$.

Use MOSFET's for the resistors too---

2A
7

